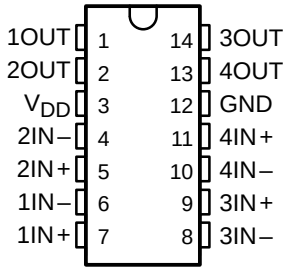
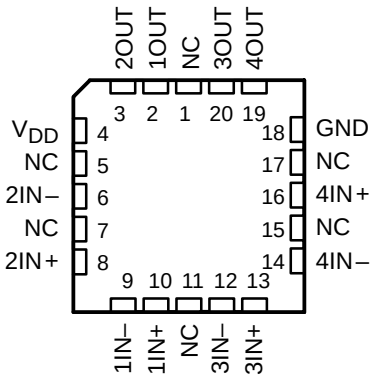
- **Single- or Dual-Supply Operation**
- **Wide Range of Supply Voltages 2 V to 18 V**
- **Very Low Supply Current Drain 0.3 mA Typ at 5 V**
- **Fast Response Time . . . 200 ns Typ for TTL-Level Input Step**
- **Built-In ESD Protection**
- **High Input Impedance . . . $10^{12}$ Ω Typ**
- **Extremely Low Input Bias Current 5 pA Typ**
- **Ultrastable Low Input Offset Voltage**
- **Input Offset Voltage Change at Worst-Case Input Conditions Typically 0.23 μV/Month, Including the First 30 Days**
- **Common-Mode Input Voltage Range Includes Ground**
- **Outputs Compatible With TTL, MOS, and CMOS**
- **Pin-Compatible With LM339**

**D, J, N, OR PW PACKAGE**
**(TOP VIEW)**




**FK PACKAGE**
**(TOP VIEW)**

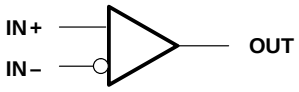



NC – No internal connection

## description

These quadruple differential comparators are fabricated using LinCMOS™ technology and consist of four independent voltage comparators designed to operate from a single power supply. Operation from dual supplies is also possible if the difference between the two supplies is 2 V to 18 V. Each device features extremely high input impedance (typically greater than $10^{12}$ Ω), allowing direct interfacing with high-impedance sources. The outputs are n-channel open-drain configurations and can be connected to achieve positive-logic wired-AND relationships.

## symbol (each comparator)




The TLC374 has internal electrostatic discharge (ESD) protection circuits and has been classified with a 1000-V ESD rating using human body model testing. However, care should be exercised in handling this device as exposure to ESD may result in degradation of the device parametric performance.

The TLC374C is characterized for operation from 0°C to 70°C. The TLC374I is characterized for operation from –40° to 85°C. The TLC374M is characterized for operation over full military temperature range of –55°C to 125°C. The TLC374Q is characterized for operation from –40°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinCMOS is a trademark of Texas Instruments Incorporated.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

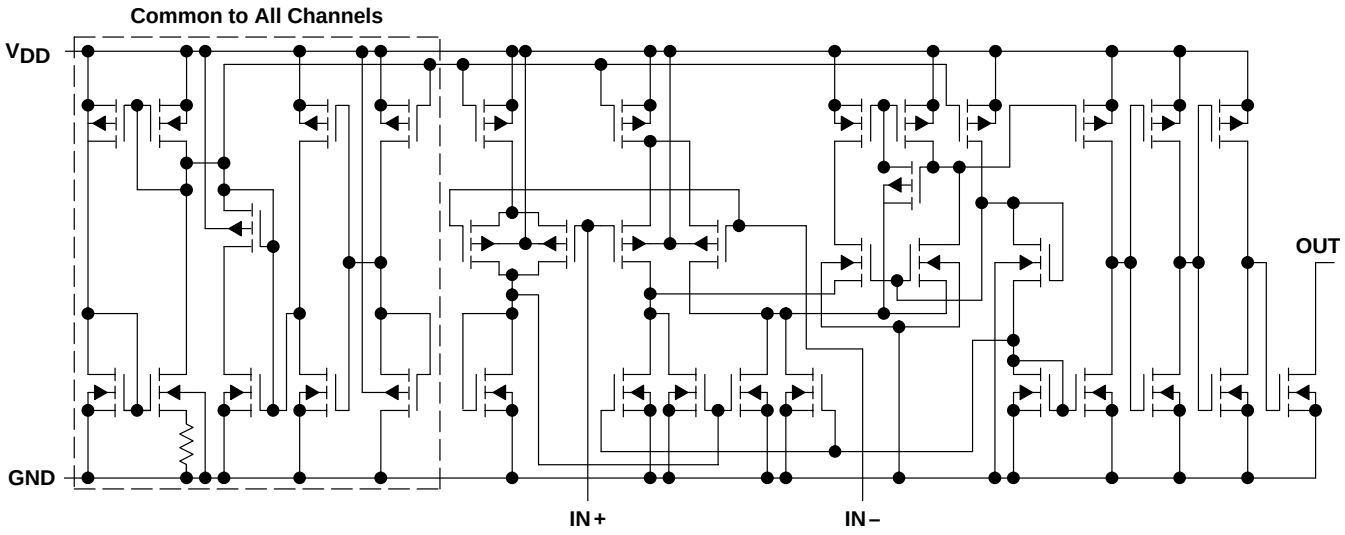
Copyright © 1999, Texas Instruments Incorporated

**AVAILABLE OPTIONS**

| $T_A$ | $V_{IO}$ max AT 25°C | PACKAGED DEVICES | | | | | CHIP FORM (Y) |
|---|---|---|---|---|---|---|---|
| | | SMALL OUTLINE (D) | CHIP CARRIER (FK) | CERAMIC DIP (J) | PLASTIC DIP (N) | TSSOP (PW) | |
| 0°C to 70°C | 5 mV | TLC374CD | — | — | TLC374CN | TLC374CPW | TLC374Y |
| –40°C to 85°C | 5 mV | TLC374ID | — | — | TLC374IN | — | — |
| –55°C to 125°C | 5 mV | TLC374MD | TLC374MFK | TLC374MJ | TLC374MN | — | — |
| –40°C to 125°C | 5 mV | TLC374QD | — | — | TLC374QN | — | — |

The D packages are available taped and reeled. Add R suffix to device type (e.g., TLC374CDR).

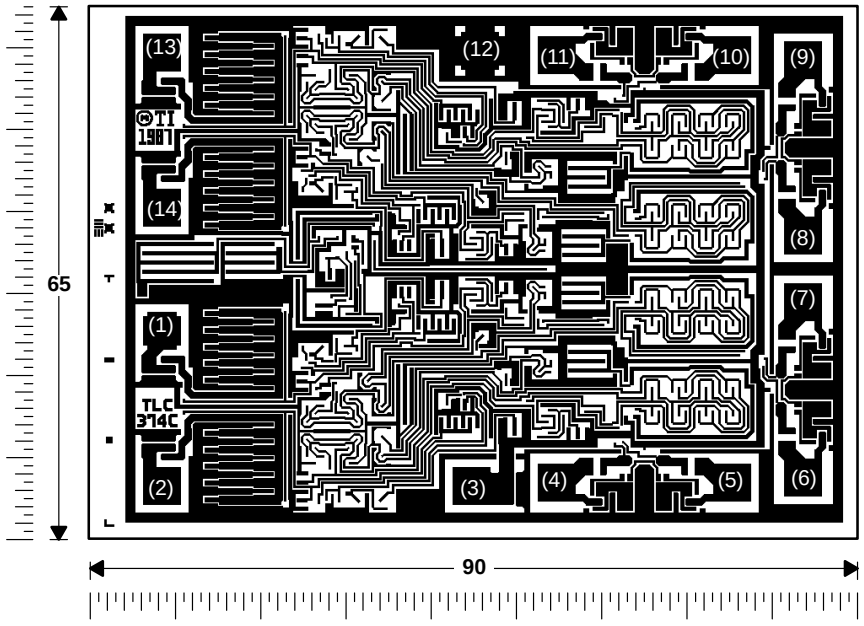
## equivalent schematic (each comparator)

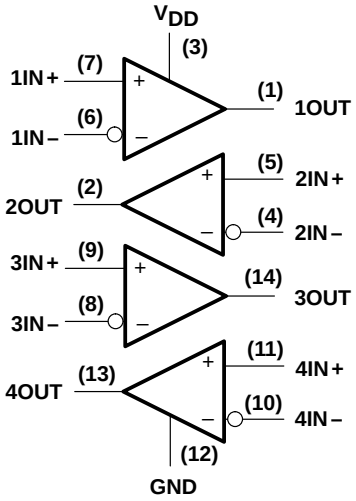


## TLC374Y chip information

This chip, when properly assembled, displays characteristics similar to the TLC374C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.

**BONDING PAD ASSIGNMENTS**




**CHIP THICKNESS: 15 TYPICAL**

**BONDING PADS: 4 × 4 MINIMUM**

**$T_{JMAX}$ = 150°C**

**TOLERANCES ARE ±10%**

**ALL DIMENSIONS ARE IN MILS.**

**PIN (12) IS INTERNALLY CONNECTED TO BACKSIDE OF CHIP.**

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{DD}$ (see Note 1) . . . . . 18 V
Differential input voltage, $V_{ID}$ (see Note 2) . . . . . ±18 V
Input voltage, $V_I$ . . . . . $V_{DD}$
Input voltage range, $V_I$ . . . . . –0.3 V to 18 V
Output voltage, $V_O$ . . . . . 18 V
Input current, $I_I$ . . . . . ±5 mA
Output current, $I_O$ . . . . . 20 mA
Duration of output short circuit to ground (see Note 3) . . . . . unlimited
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, $T_A$: TLC374C . . . . . 0°C to 70°C
TLC374I . . . . . –40°C to 85°C
TLC374M . . . . . –55°C to 125°C
TLC374Q . . . . . –40°C to 125°C
Storage temperature range, $T_{stg}$ . . . . . –65°C to 150°C
Case temperature range for 60 seconds: FK package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: D, N, or PW package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: J package . . . . . 300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values except differential voltages are with respect to network ground.
2. Differential voltages are at IN+ with respect to IN –.
3. Short circuits from outputs to $V_{DD}$ can cause excessive heating and eventual device destruction.

**DISSIPATION RATING TABLE**

| PACKAGE | $T_A \le 25°C$ POWER RATING | DERATING FACTOR | DERATE ABOVE $T_A$ | $T_A = 70°C$ POWER RATING | $T_A = 85°C$ POWER RATING | $T_A = 125°C$ POWER RATING |
|---|---|---|---|---|---|---|
| D | 500 mW | 7.6 mW/°C | 84°C | 500 mW | 494 mW | 190 mW |
| FK | 500 mW | 11.0 mW/°C | 104°C | 500 mW | 500 mW | 269 mW |
| J | 500 mW | 11.0 mW/°C | 104°C | 500 mW | 500 mW | 269 mW |
| N | 500 mW | 9.2 mW/°C | 95°C | 500 mW | 500 mW | 224 mW |
| PW | 700 mW | 5.6 mW/°C | — | 448 mW | — | — |

## recommended operating conditions

| | | TLC374C | | TLC374I | | TLC374M | | TLC374Q | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| Supply voltage, $V_{DD}$ | | 3 | 16 | 3 | 16 | 4 | 16 | 3 | 16 | V |
| Common-mode input voltage, $V_{IC}$ | $V_{DD}$ = 5 V | 0 | 3.5 | 0 | 3.5 | 0 | 3.5 | 0 | 3.5 | V |
| | $V_{DD}$ = 10 V | 0 | 8.5 | 0 | 8.5 | 0 | 8.5 | 0 | 8.5 | |
| Operating free-air temperature, $T_A$ | | 0 | 70 | –40 | 85 | –55 | 125 | –40 | 125 | °C |

## electrical characteristics at specified free-air temperature, $V_{DD}$ = 5 V

| PARAMETER | | TEST CONDITIONS | | $T_A$† | TLC374C | | | TLC374I | | | TLC374M | | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| $V_{IO}$ | Input offset voltage | $V_{IC} = V_{ICR}$min, See Note 4 | | 25°C | | 1 | 5 | | 1 | 5 | | 1 | 5 | mV |
| | | | | Full range | | | 6.5 | | | 7 | | | 10 | |
| $I_{IO}$ | Input offset current | | | 25°C | | 1 | | | 1 | | | 1 | | pA |
| | | | | MAX | | | 0.3 | | | 1 | | | 10 | nA |
| $I_{IB}$ | Input bias current | | | 25°C | | 5 | | | 5 | | | 5 | | pA |
| | | | | MAX | | | 0.6 | | | 2 | | | 20 | nA |
| $V_{ICR}$ | Common-mode input voltage range | | | 25°C | 0 to $V_{DD}-1$ | | | 0 to $V_{DD}-1$ | | | 0 to $V_{DD}-1$ | | | V |
| | | | | Full range | 0 to $V_{DD}-1.5$ | | | 0 to $V_{DD}-1.5$ | | | 0 to $V_{DD}-1.5$ | | | |
| $I_{OH}$ | High-level output current | $V_{ID}$ = 1 V | $V_{OH}$ = 5 V | 25°C | | 0.1 | | | 0.1 | | | 0.1 | | nA |
| | | | $V_{OH}$ = 15 V | Full range | | | 1 | | | 1 | | | 1 | µA |
| $V_{OL}$ | Low-level output voltage | $V_{ID}$ = –1 V, | $I_{OL}$ = 4 mA | 25°C | | 150 | 400 | | 150 | 400 | | 150 | 400 | mV |
| | | | | Full range | | | 700 | | | 700 | | | 700 | |
| $I_{OL}$ | Low-level output current | $V_{ID}$ = –1 V, | $V_{OL}$ = 1.5 V | 25°C | 6 | 16 | | 6 | 16 | | 6 | 16 | | mA |
| $I_{DD}$ | Supply current (four comparators) | $V_{ID}$ = 1 V, | No load | 25°C | | 300 | 600 | | 300 | 600 | | 300 | 600 | µA |
| | | | | Full range | | | 800 | | | 800 | | | 800 | |

† All characteristics are measured with zero common-mode input voltage unless otherwise noted. Full range is 0°C to 70°C for TLC374C, –40°C to 85°C for TLC374I, and –55°C to 125°C for the TLC374M, and –40°C to 125°C for TLC374Q. MAX is 70°C for TLC374C, 85°C TLC374I, and 125°C for the TLC374M, and 125°C for TLC374Q. IMPORTANT: See Parameter Measurement Information.

NOTE 4: The offset voltage limits given are the maximum values required to drive the output above 4 V or below 400 mV with a 10-kΩ resistor between the output and $V_{DD}$. They can be verified by applying the limit value to the input and checking for the appropriate output state.

## switching characteristics, $V_{DD}$ = 5 V, $T_A$ = 25°C

| PARAMETER | TEST CONDITIONS | | TLC374C, TLC374I TLC374M, TLC374Q | | | UNIT |
|---|---|---|---|---|---|---|
| | | | MIN | TYP | MAX | |
| Response time | $R_L$ connected to 5 V through 5.1 kΩ, $C_L$ = 15 pF‡, See Note 5 | 100-mV input step with 5-mV overdrive | | 650 | | ns |
| | | TTL-level input step | | 200 | | |

‡ $C_L$ includes probe and jig capacitance.

NOTE 5: The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.

## electrical characteristics at specified free-air temperature, $V_{DD}$ = 5 V, $T_A$ = 25°C (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | TLC374Y | | | UNIT |
|---|---|---|---|---|---|---|---|
| | | | | MIN | TYP | MAX | |
| $V_{IO}$ | Input offset voltage | $V_{IC}$ = $V_{ICR}$min, | See Note 4 | | 1 | 5 | mV |
| $I_{IO}$ | Input offset current | | | | 1 | | pA |
| $I_{IB}$ | Input bias current | | | | 5 | | pA |
| $V_{ICR}$ | Common-mode input voltage range | | | 0 to $V_{DD}$–1 | | | V |
| $I_{OH}$ | High-level output current | $V_{ID}$ = 1 V, | $V_{OH}$ = 5 V | | 0.1 | | nA |
| $V_{OL}$ | Low-level output voltage | $V_{ID}$ = –1 V, | $I_{OL}$ = 4 mA | | 150 | 400 | mV |
| $I_{OL}$ | Low-level output current | $V_{ID}$ = –1 V, | $V_{OL}$ = 1.5 mV | 6 | 16 | | mA |
| $I_{DD}$ | Supply current (four comparators) | $V_{ID}$ =1 V, | No load | | 300 | 600 | µA |

NOTE 4: The offset voltage limits given are the maximum values required to drive the output above 4 V or below 400 mV with a 10-kΩ resistor between the output and $V_{DD}$. They can be verified by applying the limit value to the input and checking for the appropriate output state.

## switching characteristics, $V_{DD}$ = 5 V, $T_A$ = 25°C

| PARAMETER | TEST CONDITIONS | | TLC374Y | | | UNIT |
|---|---|---|---|---|---|---|
| | | | MIN | TYP | MAX | |
| Response time | $R_L$ connected to 5 V through 5.1 kΩ, $C_L$ = 15 pF†, See Note 5 | 100-mV input step with 5-mV overdrive | | 650 | | ns |
| | | TTL-level input step | | 200 | | |

† $C_L$ includes probe and jig capacitance.

NOTE 4: The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.

## PARAMETER MEASUREMENT INFORMATION

The digital output stage of the TLC374 can be damaged if it is held in the linear region of the transfer curve. Conventional operational amplifier/comparator testing incorporates the use of a servo loop that is designed to force the device output to a level within this linear region. Since the servo-loop method of testing cannot be used, the following alternative for measuring parameters such as input offset voltage, common-mode rejection, etc., are offered.

To verify that the input offset voltage falls within the limits specified, the limit value is applied to the input as shown in Figure 1(a). With the noninverting input positive with respect to the inverting input, the output should be high. With the input polarity reversed, the output should be low.

A similar test can be made to verify the input offset voltage at the common-mode extremes. The supply voltages can be slewed as shown in Figure 1(b) for the $V_{ICR}$ test, rather than changing the input voltages, to provide greater accuracy.

A close approximation of the input offset voltage can be obtained by using a binary search method to vary the differential input voltage while monitoring the output state. When the applied input voltage differential is equal, but opposite in polarity to the input offset voltage, the output changes state.

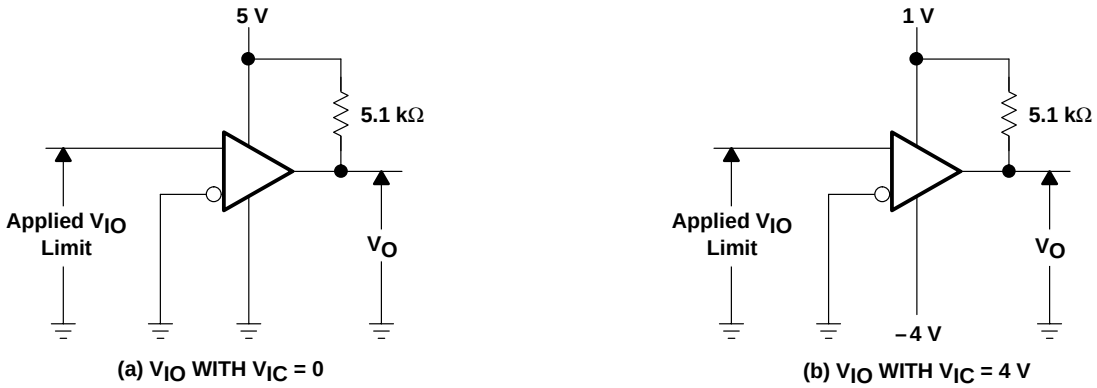



**Figure 1. Method for Verifying That Input Offset Voltage is Within Specified Limits**

## PARAMETER MEASUREMENT INFORMATION

Figure 2 illustrates a practical circuit for direct dc measurement of input offset voltage that does not bias the comparator into the linear region. The circuit consists of a switching-mode servo loop in which U1a generates a triangular waveform of approximately 20-mV amplitude. U1b acts as a buffer with C2 and R4 removing any residual dc offset. The signal is then applied to the inverting input of the comparator under test, while the noninverting input is driven by the output of the integrator formed by U1c through the voltage divider formed by R9 and R10. The loop reaches a stable operating point when the output of the comparator under test has a duty cycle of exactly 50%, which can only occur when the incoming triangle wave is sliced symmetrically or when the voltage at the noninverting input exactly equals the input offset voltage.

Voltage divider R9 and R10 provide a step up of the input offset voltage by a factor of 100 to make measurement easier. The values of R5, R8, R9, and R10 can significantly influence the accuracy of the reading; therefore, it is suggested that their tolerance level be 1% or lower.

Measuring the extremely low values of input current requires isolation from all other sources of leakage current and compensation for the leakage of the test socket and board. With a good picoammeter, the socket and board leakage can be measured with no device in the socket. Subsequently, this open-socket leakage value can be subtracted from the measurement obtained with a device in the socket to obtain the actual input current of the device.

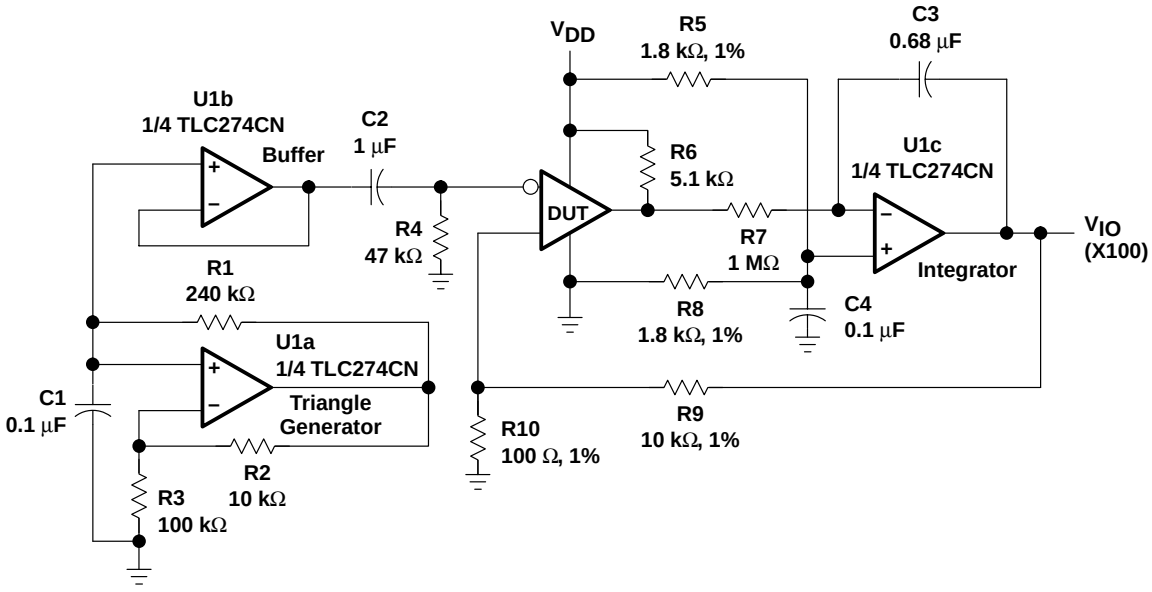
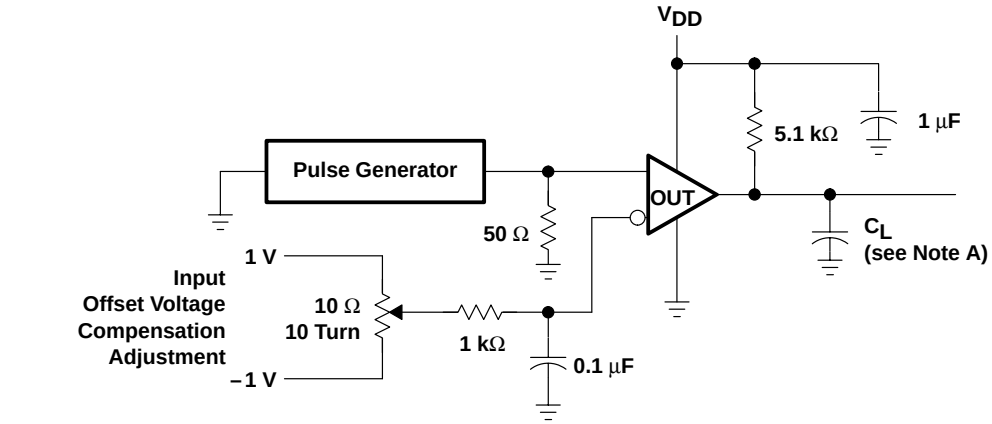


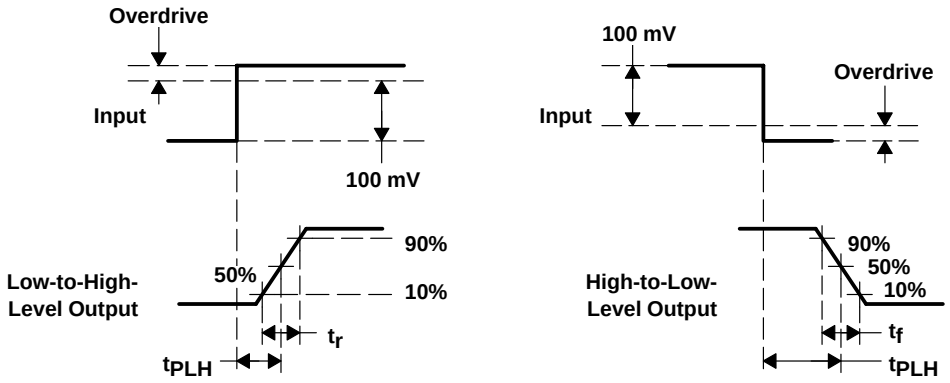

**Figure 2. Test Circuit for Input Offset Voltage Measurement**

## PARAMETER MEASUREMENT INFORMATION

Response time is defined as the interval between the application of an input step function and the instant when the output reaches 50% of its maximum value. Response time, low-to-high-level output, is measured from the trailing edge of the input pulse. Response-time measurement at low input signal levels can be greatly affected by the input offset voltage. The offset voltage should be balanced by the adjustment at the inverting input (as shown in Figure 3) so that the circuit is just at the transition point. Then a low signal, for example, 105-mV or 5-mV overdrive, causes the output to change state.




TEST CIRCUIT




VOLTAGE WAVEFORMS

NOTE A: $C_L$ includes probe and jig capacitance.

**Figure 3. Response, Rise, and Fall Times Test Circuit and Voltage Waveforms**

## PRINCIPLES OF OPERATION

### LinCMOS process

LinCMOS process is a linear polysilicon-gate complimentary-MOS process. Primarily designed for single-supply applications, LinCMOS products facilitate the design of a wide range of high-performance analog functions from operational amplifiers to complex mixed-mode converters.

While digital designers are experienced with CMOS, MOS technologies are relatively new for analog designers. This short guide is intended to answer the most frequently asked questions related to the quality and reliability of LinCMOS products. Further questions should be directed to the nearest TI field sales office.

### electrostatic discharge

CMOS circuits are prone to gate oxide breakdown when exposed to high voltages even if the exposure is only for very short periods of time. Electrostatic discharge (ESD) is one of the most common causes of damage to CMOS devices. It can occur when a device is handled without proper consideration for environmental electrostatic charges, e.g. during board assembly. If a circuit in which one amplifier from a dual operational amplifier is being used and the unused pins are left open, high voltages tends to develop. If there is no provision for ESD protection, these voltages may eventually punch through the gate oxide and cause the device to fail. To prevent voltage buildup, each pin is protected by internal circuitry.

Standard ESD-protection circuits safely shunt the ESD current by providing a mechanism whereby one or more transistors break down at voltages higher than normal operating voltages but lower than the breakdown voltage of the input gate. This type of protection scheme is limited by leakage currents which flow through the shunting transistors during normal operation after an ESD voltage has occurred. Although these currents are small, on the order of tens of nanoamps, CMOS amplifiers are often specified to draw input currents as low as tens of picoamps.

To overcome this limitation, TI design engineers developed the patented ESD-protection circuit shown in Figure 4. This circuit can withstand several successive 1-kV ESD pulses, while reducing or eliminating leakage currents that may be drawn through the input pins. A more detailed discussion of the operation of TI's ESD-protection circuit is presented on the next page.

All input an output pins of LinCMOS and Advanced LinCMOS products have associated ESD-protection circuitry that undergoes qualification testing to withstand 1000 V discharged from a 100-pF capacitor through a 1500-Ω resistor (human body model) and 200 V from a 100-pF capacitor with no current-limiting resistor (charged device model). These tests simulate both operator and machine handling of devices during normal test and assembly operations.

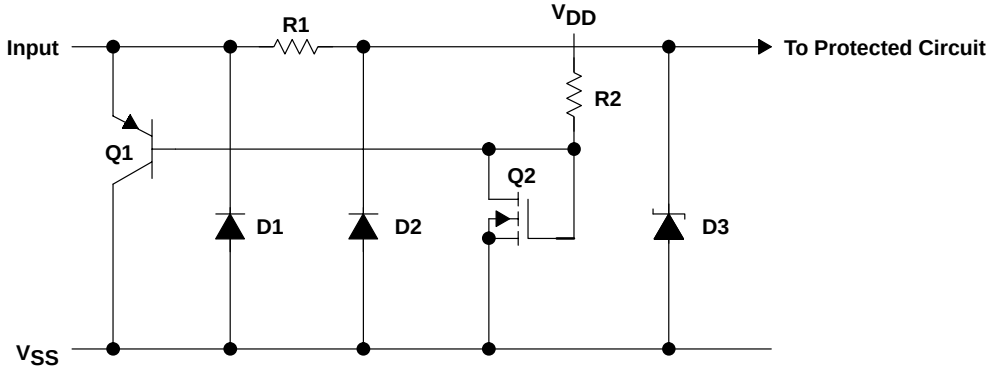



**Figure 4. LinCMOS ESD-Protection Schematic**

## PRINCIPLES OF OPERATION

### Input protection circuit operation

Texas Instruments patented protection circuitry allows for both positive- and negative-going ESD transients. These transients are characterized by extremely fast rise times and usually low energies, and can occur both when the device has all pins open and when it is installed in a circuit.

### positive ESD transients

Initial positive charged energy is shunted through Q1 to $V_{SS}$. Q1 turns on when the voltage at the input rises above the voltage on $V_{DD}$ by a value equal to the $V_{EB}$ of Q1. The base current increases through R2 with input current as Q1 saturates. The base current through R2 as Q1 saturates forces the voltage at the drain and gate of Q2 to exceed its threshold level ($V_T$ ~ 22 to 26 V) and turn on Q2. The shunted input current through Q1 to $V_{SS}$ is now shunted through the n-channel enhancement-type MOSFET Q2 to $V_{SS}$. If the voltage on the input pin continues to rise, the breakdown voltage of d3 is exceeded and all remaining energy is dissipated in R1 and D3. The breakdown voltage of D3 is designed to be 24 V to 27 V, which is well below the gate oxide voltage of the circuit to be protected.

### negative ESD transients

The negative charged ESD transients are shunted directly through D1. Additional energy is dissipated in R1 and D2 as D2 becomes forward-biased. The voltage seen by the protected circuit is –0.3 V to –1 V (the forward voltage of D1 and D2).

### circuit-design considerations

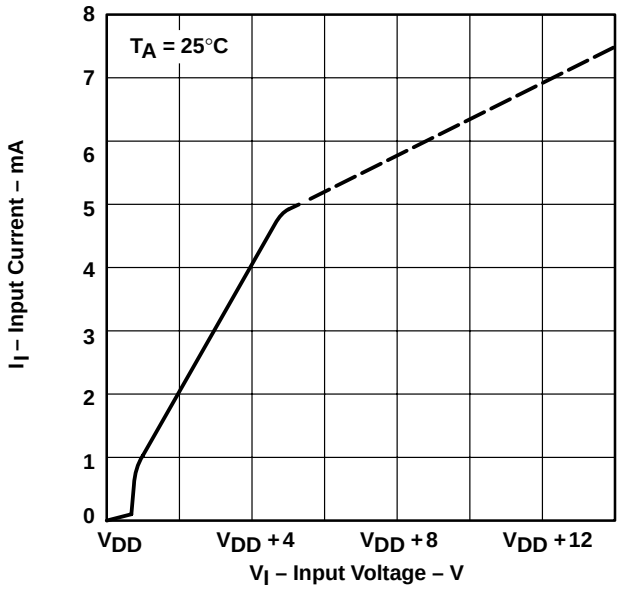
LinCMOS products are being used in actual circuits environments that have input voltages that exceed the recommended common-mode input voltage range and activate the input protection circuit. Even under normal operation, these conditions occur during circuit power up or power down, and in many cases, when the device is being used for a signal conditioning function. The input voltages can exceed $V_{ICR}$ and not damage the device only if the inputs are current limited. The recommended current limit shown on most product data sheets is ±5 mA. Figures 5 and 6 show typical characteristics for input voltage vs input current.

Normal operation and correct output state can be expected even when the input voltage exceeds the positive supply voltage. The input current should be externally limited even through internal positive current limiting is achieved in the input protection circuit by the action of Q1. When Q1 is on, it saturates and limits the current to approximately 5-mA collector current by design. When saturated, Q1 base current increases with input current. This current is forced into the $V_{DD}$ pin and into the device $I_{DD}$ or the $V_{DD}$ supply through R2 producing the current limiting effects shown in Figure 5. This internal limiting lasts only as long as the input voltage is below the $V_T$ of Q2.

When the input voltage exceeds the negative supply voltage, normal operation is affected and output voltage states may not be correct. Also, the isolation between channels of multiple devices (duals and quads) can be severely affected. External current limiting must be used since this current is directly shunted by D1 and D2, and no internal limiting is achieved. If normal output voltage states are required, an external input voltage clamp is required (see Figure 7).

## PRINCIPLES OF OPERATION

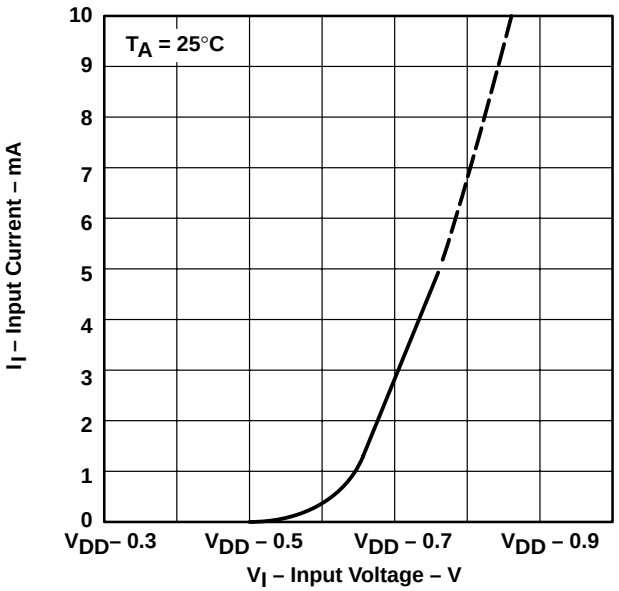
**INPUT CURRENT vs INPUT VOLTAGE†**




† The dashed line identifies an area of operation where some degradation of parametric performance may be experienced.

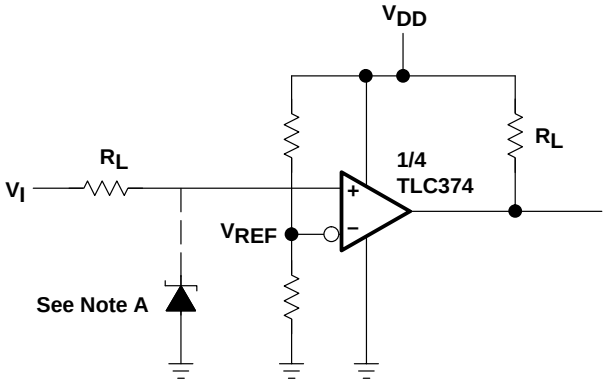
**Figure 5**

**INPUT CURRENT vs INPUT VOLTAGE†**




† The dashed line identifies an area of operation where some degradation of parametric performance may be experienced.

**Figure 6**




**Positive Voltage Input Current Limit:**

$$R_I = \frac{+V_I - V_{DD} - 0.3\ V}{5\ mA}$$

**Negative Voltage Input Current Limit:**

$$R_I = \frac{-V_I - V_{DD} - (0.3\ V)}{5\ mA}$$

NOTE A: If the correct output state is required when the negative input exceeds $V_{SS}$, a Schotty clamp is required.

**Figure 7. Typical Input Current-Limiting Configuration for a LinCMOS Comparator**

## PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| 5962-87659012A | Active | Production | LCCC (FK) \| 20 | 55 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962-87659012A TLC374MFKB |
| 5962-8765901CA | Active | Production | CDIP (J) \| 14 | 25 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962-8765901CA TLC374MJB |
| TLC374CD | Obsolete | Production | SOIC (D) \| 14 | - | - | Call TI | Call TI | 0 to 70 | TLC374C |
| TLC374CDR | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC374C |
| TLC374CDR.A | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC374C |
| TLC374CN | Active | Production | PDIP (N) \| 14 | 25 \| TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | TLC374CN |
| TLC374CN-A | Active | Production | PDIP (N) \| 14 | 25 \| TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | TLC374CN_A |
| TLC374CN-A.A | Active | Production | PDIP (N) \| 14 | 25 \| TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | TLC374CN_A |
| TLC374CN.A | Active | Production | PDIP (N) \| 14 | 25 \| TUBE | Yes | NIPDAU | N/A for Pkg Type | 0 to 70 | TLC374CN |
| TLC374CNS | Active | Production | SOP (NS) \| 14 | 50 \| TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC374 |
| TLC374CNS.A | Active | Production | SOP (NS) \| 14 | 50 \| TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC374 |
| TLC374CPW | Active | Production | TSSOP (PW) \| 14 | 90 \| TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | P374 |
| TLC374CPW.A | Active | Production | TSSOP (PW) \| 14 | 90 \| TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | P374 |
| TLC374CPWR | Active | Production | TSSOP (PW) \| 14 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | P374 |
| TLC374CPWR.A | Active | Production | TSSOP (PW) \| 14 | 2000 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | P374 |
| TLC374ID | Obsolete | Production | SOIC (D) \| 14 | - | - | Call TI | Call TI | -40 to 85 | TLC374I |
| TLC374IDR | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TLC374I |
| TLC374IDR.A | Active | Production | SOIC (D) \| 14 | 2500 \| LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | TLC374I |
| TLC374IN | Active | Production | PDIP (N) \| 14 | 25 \| TUBE | Yes | NIPDAU | N/A for Pkg Type | -40 to 85 | TLC374IN |
| TLC374IN.A | Active | Production | PDIP (N) \| 14 | 25 \| TUBE | Yes | NIPDAU | N/A for Pkg Type | -40 to 85 | TLC374IN |
| TLC374MD | Obsolete | Production | SOIC (D) \| 14 | - | - | Call TI | Call TI | -55 to 125 | |
| TLC374MDG4 | Obsolete | Production | SOIC (D) \| 14 | - | - | Call TI | Call TI | - | |
| TLC374MFKB | Active | Production | LCCC (FK) \| 20 | 55 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962-87659012A TLC374MFKB |
| TLC374MFKB.A | Active | Production | LCCC (FK) \| 20 | 55 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962-87659012A TLC374MFKB |

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| TLC374MJ | Active | Production | CDIP (J) \| 14 | 25 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | TLC374MJ |
| TLC374MJ.A | Active | Production | CDIP (J) \| 14 | 25 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | TLC374MJ |
| TLC374MJB | Active | Production | CDIP (J) \| 14 | 25 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962-8765901CA TLC374MJB |
| TLC374MJB.A | Active | Production | CDIP (J) \| 14 | 25 \| TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962-8765901CA TLC374MJB |

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TLC374, TLC374M :**

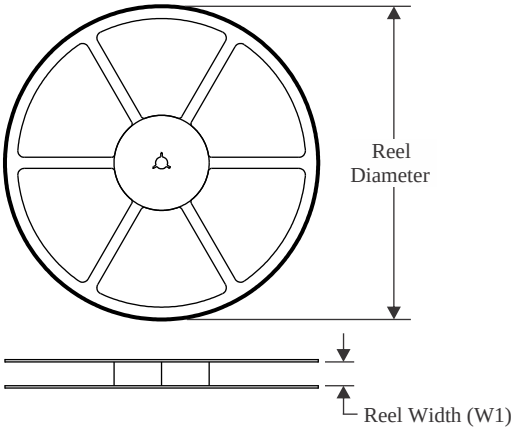
- Catalog : TLC374
- Military : TLC374M

NOTE: Qualified Version Definitions:

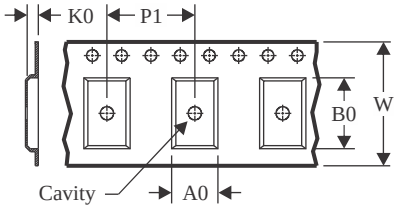
- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

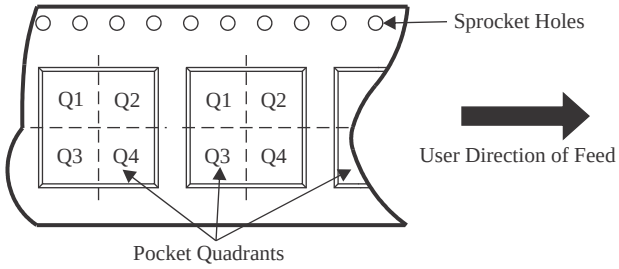



**TAPE DIMENSIONS**




| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

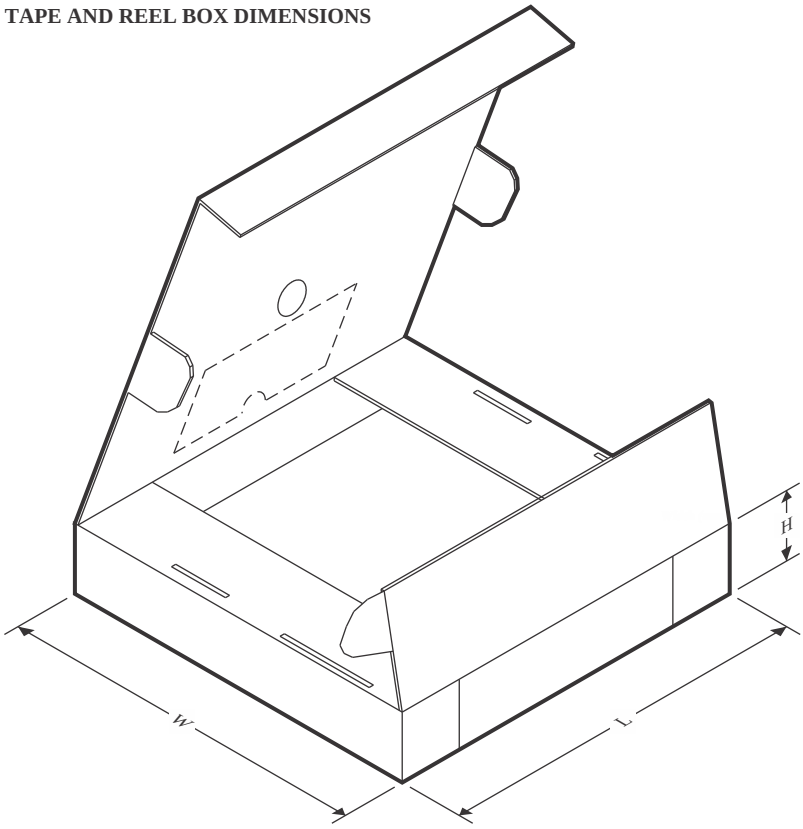
**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| TLC374CDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC374CDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC374CPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TLC374IDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |

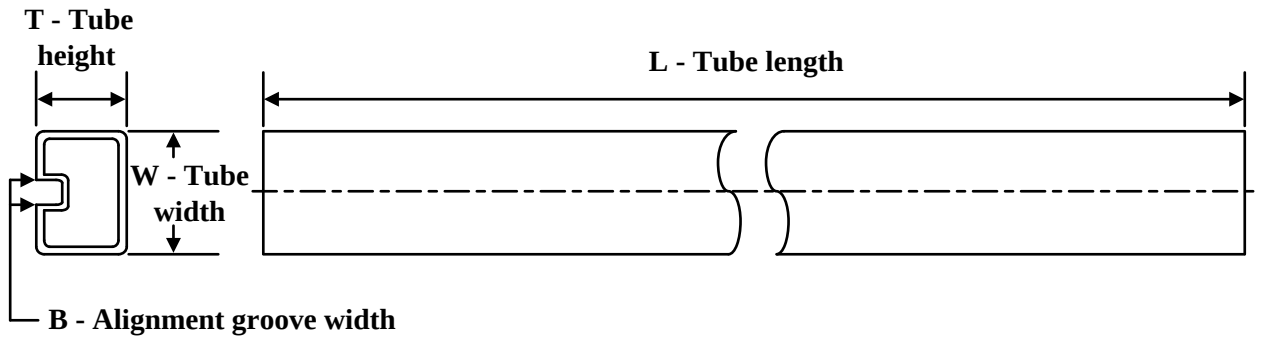
TAPE AND REEL BOX DIMENSIONS




*All dimensions are nominal

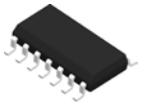
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| TLC374CDR | SOIC | D | 14 | 2500 | 356.0 | 356.0 | 35.0 |
| TLC374CDR | SOIC | D | 14 | 2500 | 353.0 | 353.0 | 32.0 |
| TLC374CPWR | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| TLC374IDR | SOIC | D | 14 | 2500 | 353.0 | 353.0 | 32.0 |

## TUBE




*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|---|---|---|---|---|---|---|---|---|
| 5962-87659012A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| TLC374CN | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLC374CN-A | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLC374CN-A.A | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLC374CN.A | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLC374CNS | NS | SOP | 14 | 50 | 530 | 10.5 | 4000 | 4.1 |
| TLC374CNS.A | NS | SOP | 14 | 50 | 530 | 10.5 | 4000 | 4.1 |
| TLC374CPW | PW | TSSOP | 14 | 90 | 530 | 10.2 | 3600 | 3.5 |
| TLC374CPW.A | PW | TSSOP | 14 | 90 | 530 | 10.2 | 3600 | 3.5 |
| TLC374IN | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLC374IN.A | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLC374MFKB | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| TLC374MFKB.A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |

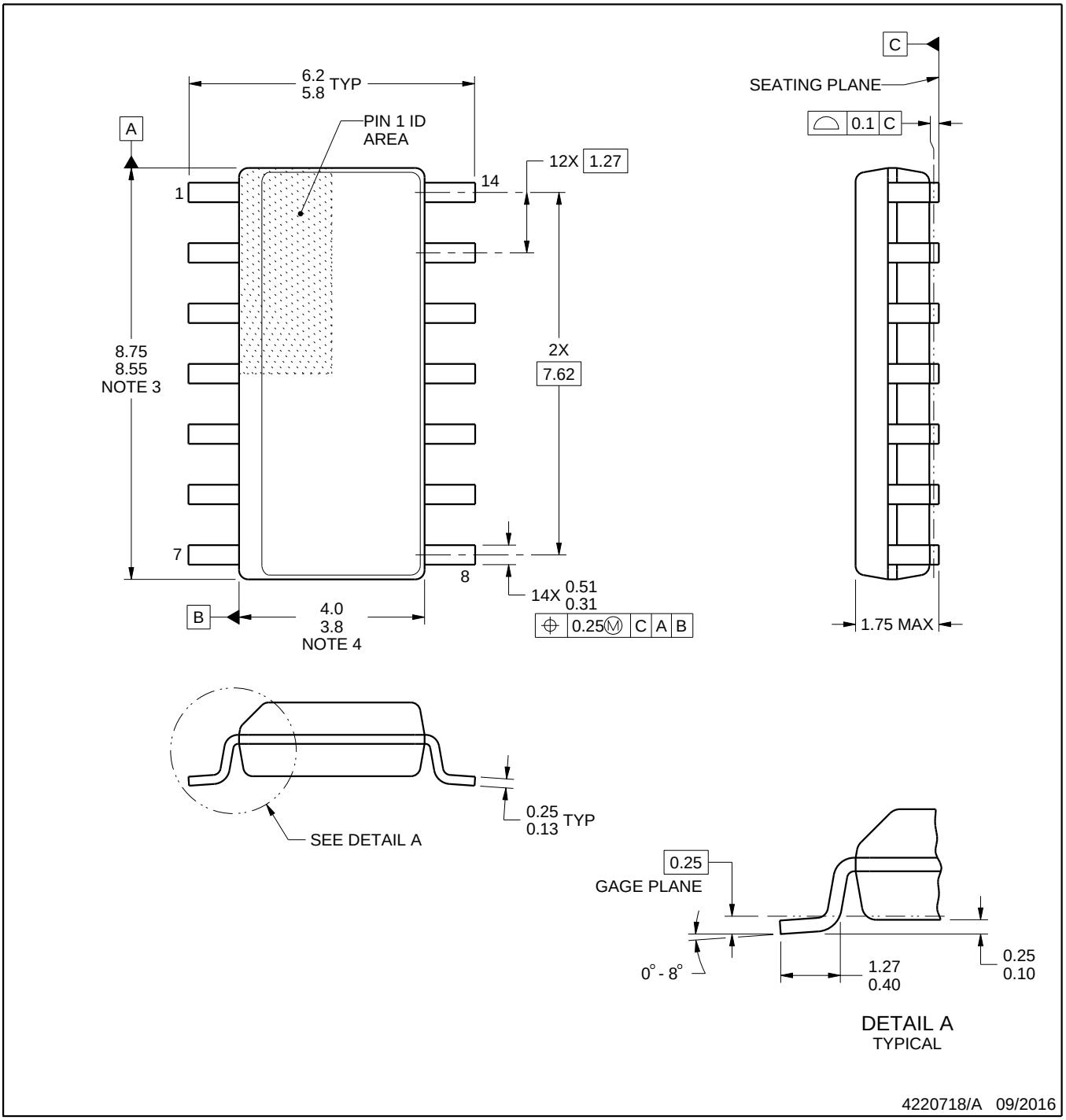


# PACKAGE OUTLINE

## D0014A

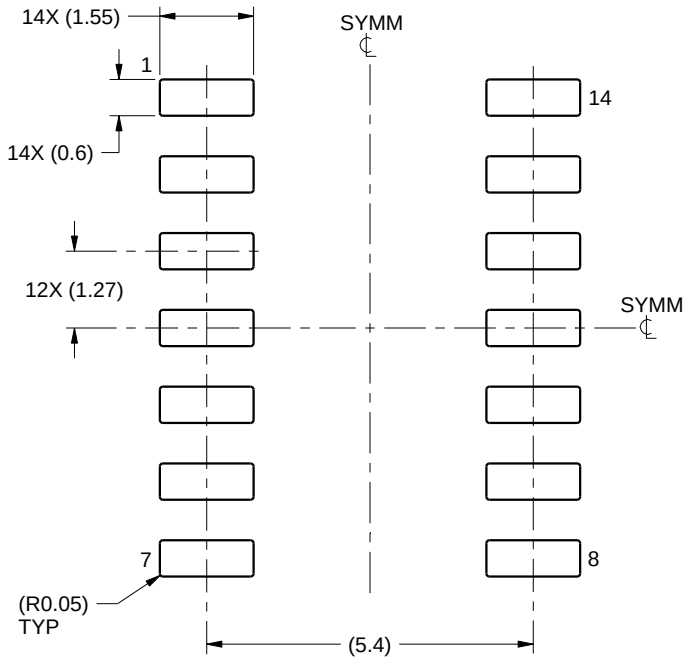
## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

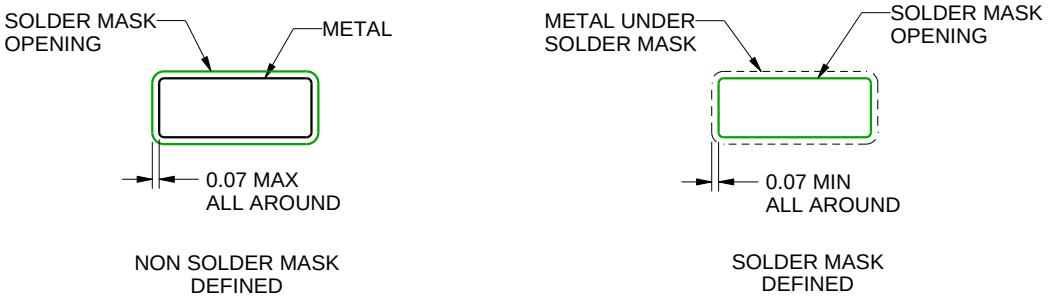



NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.




LAND PATTERN EXAMPLE
SCALE:8X




SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

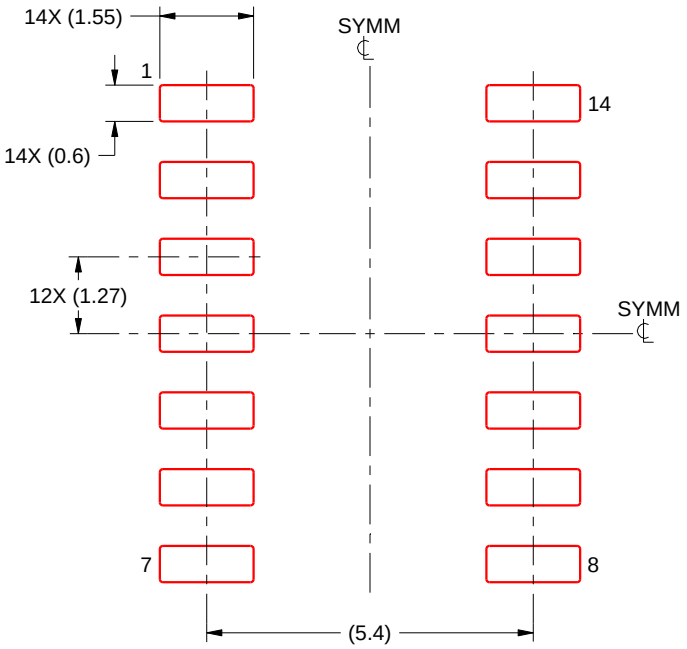
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

## D0014A

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT




SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

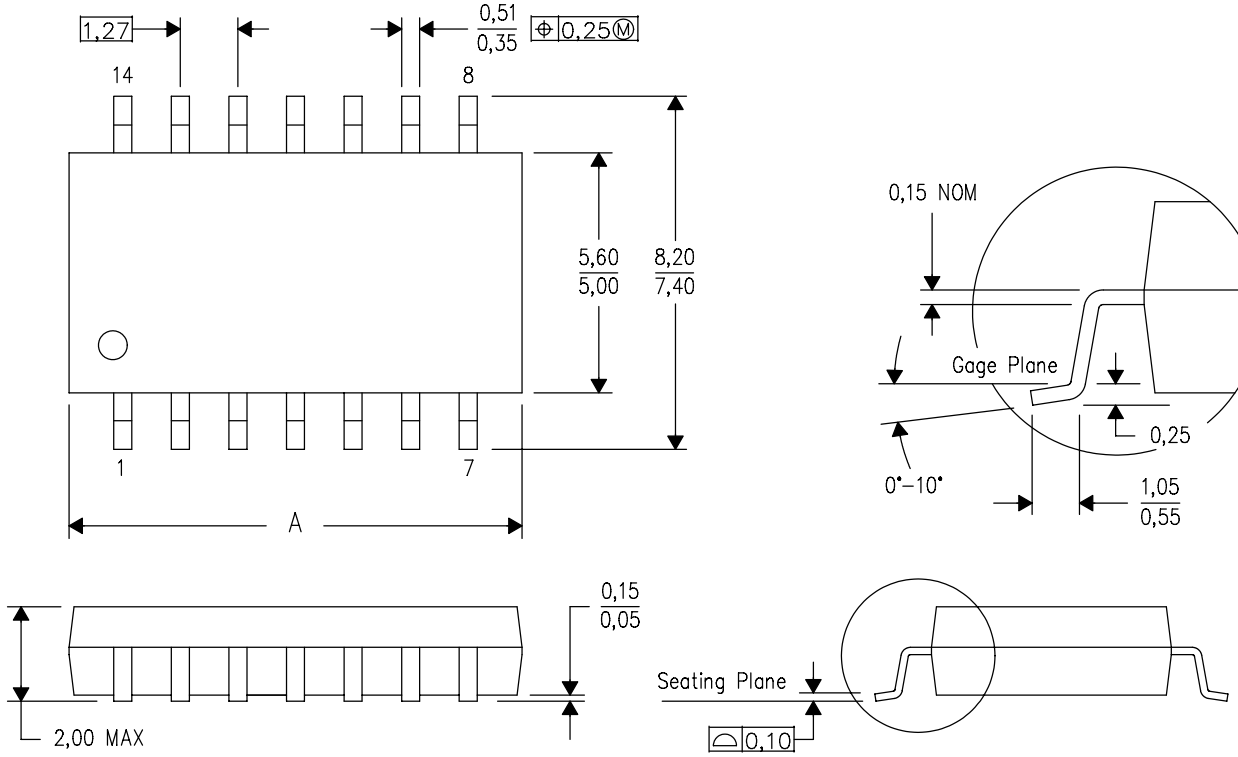
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## MECHANICAL DATA

**NS (R-PDSO-G**)** **PLASTIC SMALL-OUTLINE PACKAGE**

**14-PINS SHOWN**




| DIM \ PINS ** | 14 | 16 | 20 | 24 |
|---|---|---|---|---|
| A MAX | 10,50 | 10,50 | 12,90 | 15,30 |
| A MIN | 9,90 | 9,90 | 12,30 | 14,70 |

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

# GENERIC PACKAGE VIEW

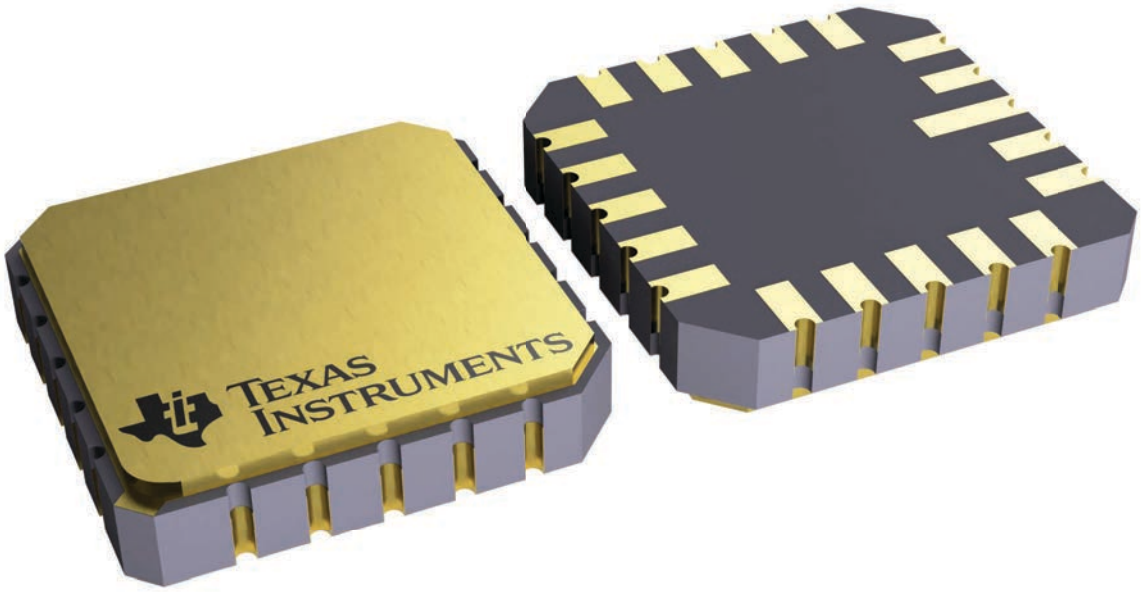
## FK 20

## LCCC - 2.03 mm max height

**8.89 x 8.89, 1.27 mm pitch**

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

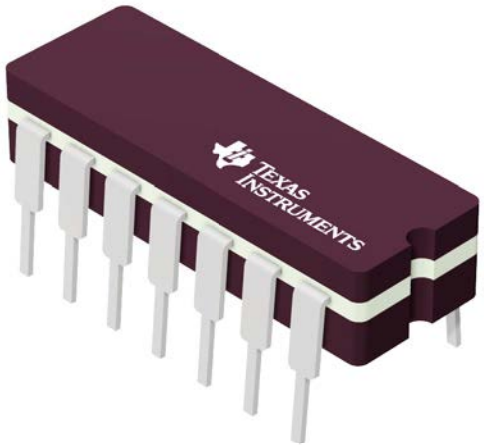



4229370VA\

# GENERIC PACKAGE VIEW

## J 14 CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE




Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4040083-5/G

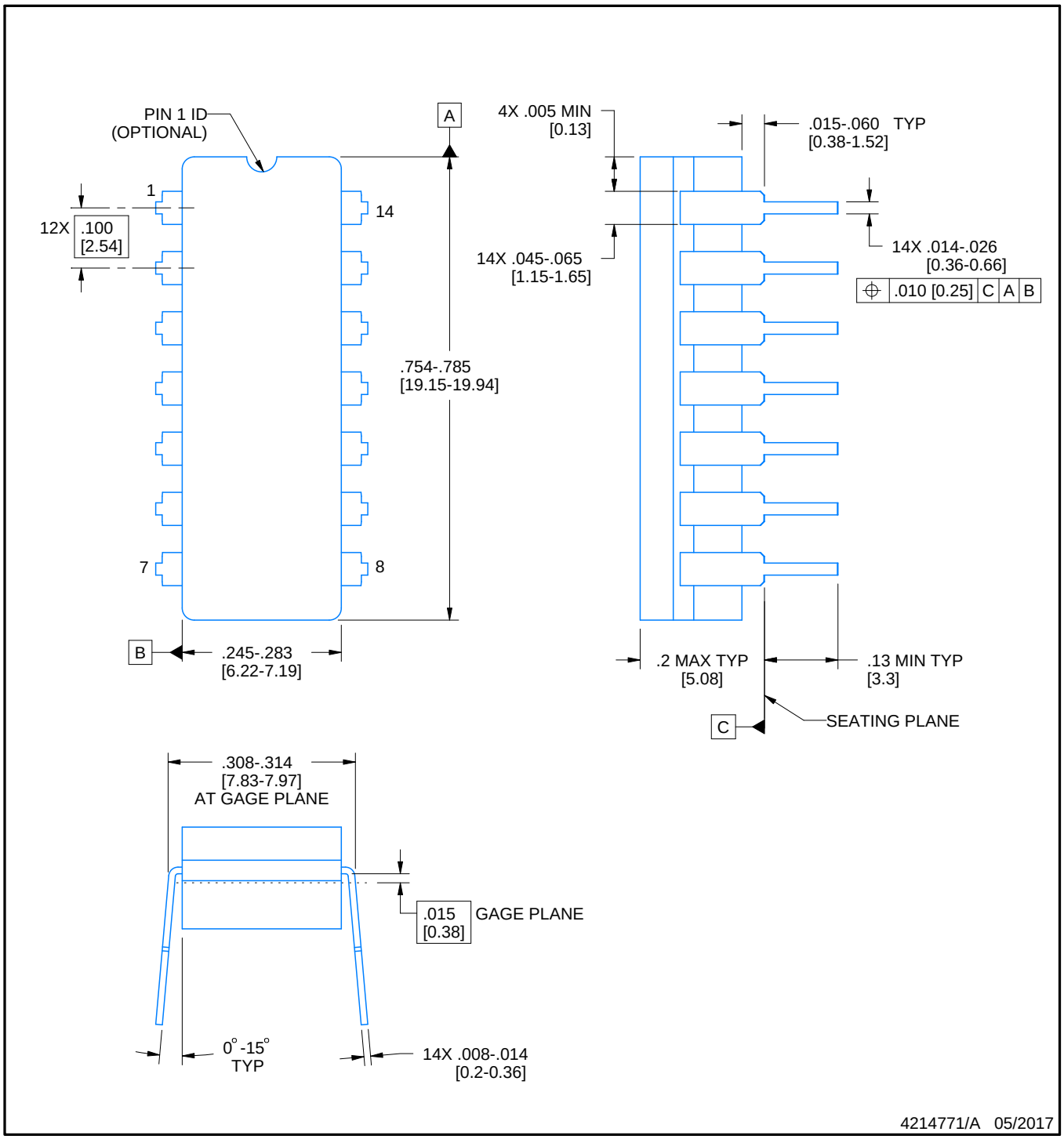


# PACKAGE OUTLINE

## J0014A

## CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE




NOTES:

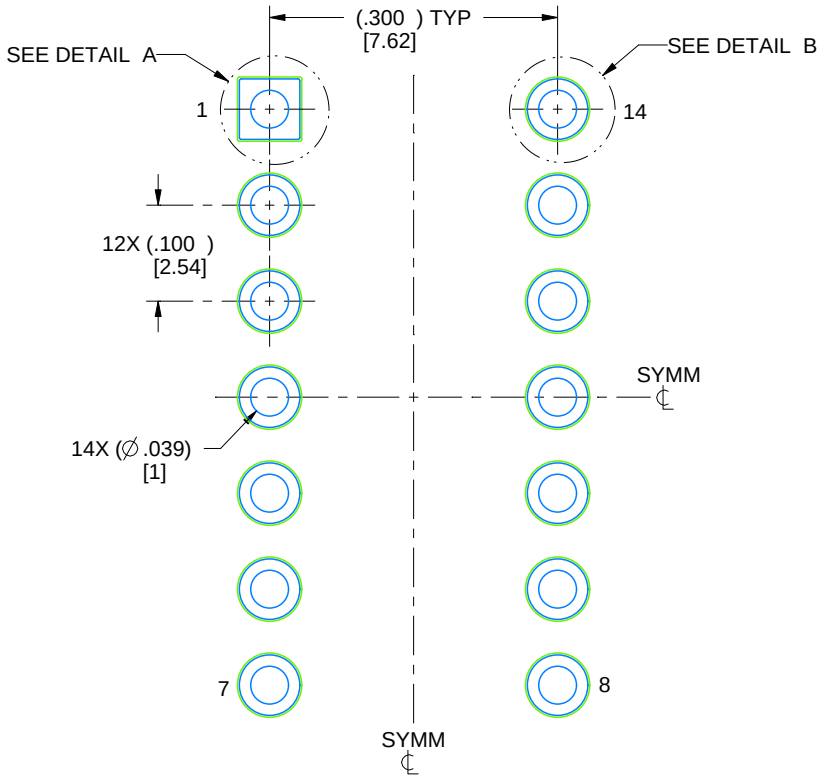
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package is hermitically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
5. Falls within MIL-STD-1835 and GDIP1-T14.

# EXAMPLE BOARD LAYOUT

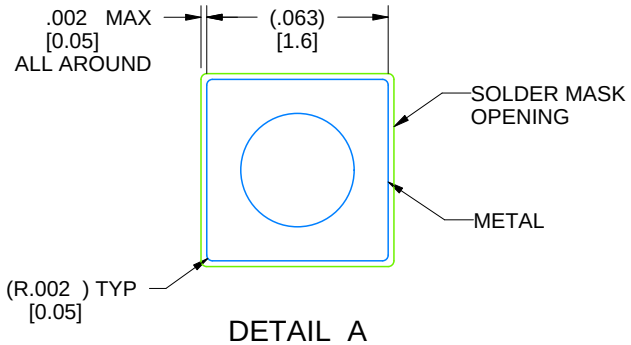
## J0014A

## CDIP - 5.08 mm max height

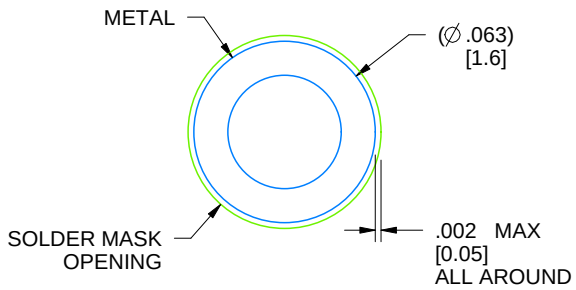
CERAMIC DUAL IN LINE PACKAGE




LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE: 5X




DETAIL A
SCALE: 15X



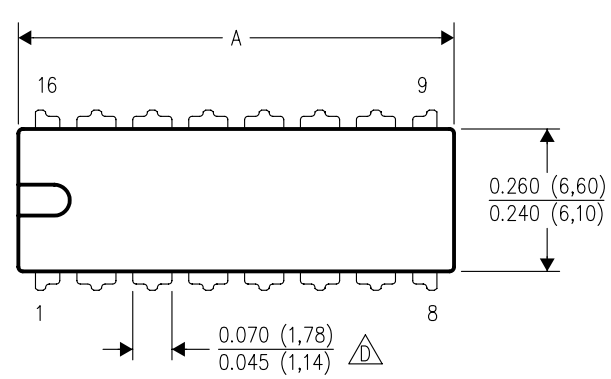

DETAIL B
13X, SCALE: 15X

4214771/A 05/2017

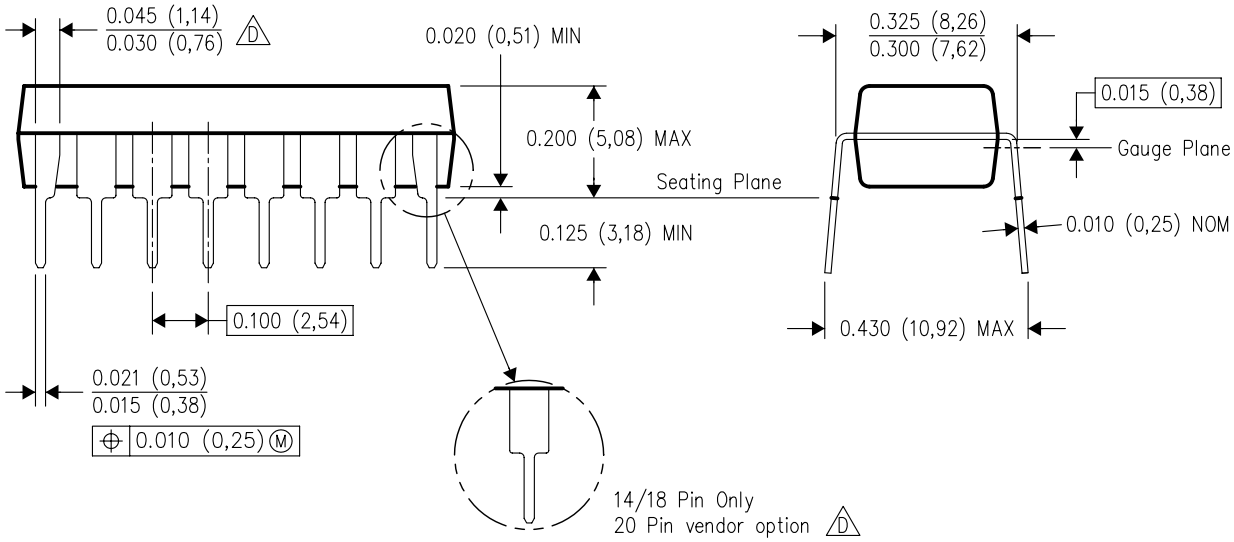
## N (R–PDIP–T**)

## PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN




| DIM \ PINS ** | 14 | 16 | 18 | 20 |
|---|---|---|---|---|
| A MAX | 0.775 (19,69) | 0.775 (19,69) | 0.920 (23,37) | 1.060 (26,92) |
| A MIN | 0.745 (18,92) | 0.745 (18,92) | 0.850 (21,59) | 0.940 (23,88) |
| MS–001 VARIATION (C) | AA | BB | AC | AD |




4040049/E 12/2002

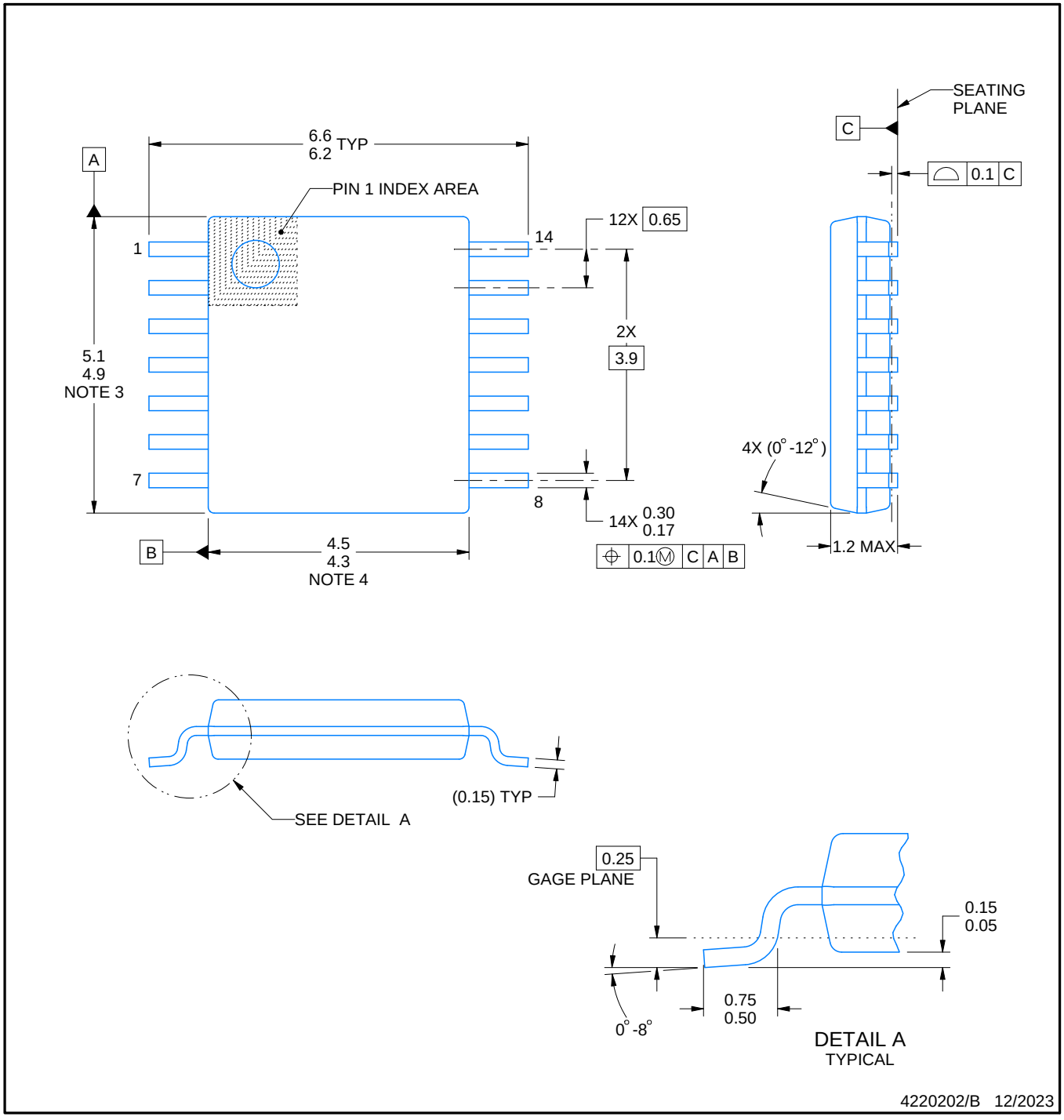
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

# PACKAGE OUTLINE

## PW0014A

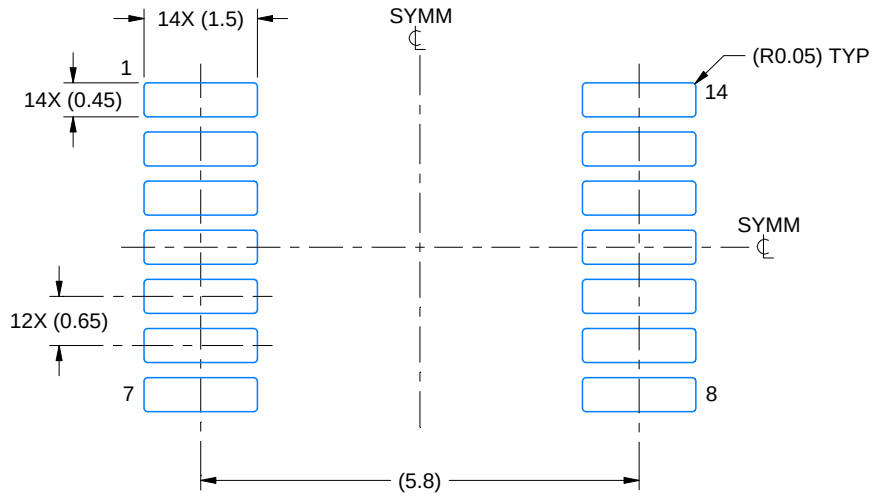
## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

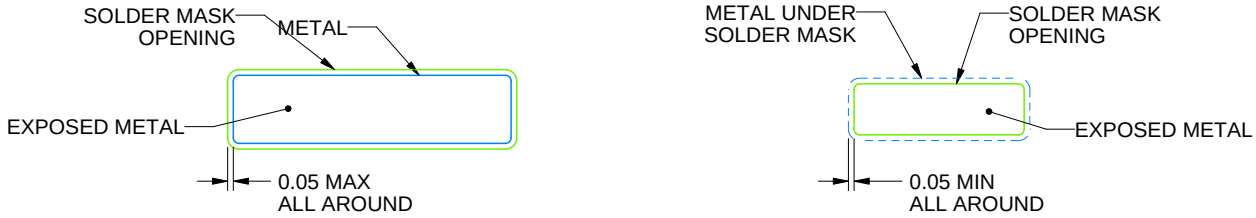



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

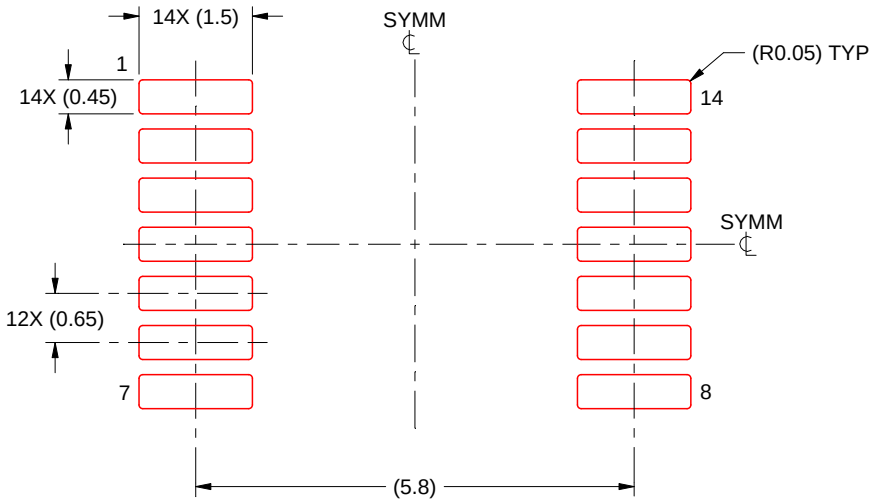



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.




SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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